AUTOMOTIV

COMPLIANT

HALOGEN FREE

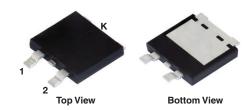


## Vishay General Semiconductor

# Dual High-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.56 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 

### eSMP® Series SMPD (TO-263AC)





#### **DESIGN SUPPORT TOOLS AVAILABLE**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 5 A			
$V_{RRM}$	150 V			
I <sub>FSM</sub>	80 A			
$V_F$ at $I_F = 5$ A ( $T_J = 125$ °C)	0.63 V			
T <sub>J</sub> max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V10DM153C	UNIT	
Device marking code			V10DM153C		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub> 150		V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub> (1)	10		
	per diode		5	А	
Peak forward surge current 8.3 ms single half superimposed on rated load	sine-wave	I <sub>FSM</sub>	80	А	
Operating junction temperature range		T <sub>J</sub> <sup>(2)</sup>	-40 to +175	00	
Storage temperature range		T <sub>STG</sub>	-55 to +175	°C	

#### **Notes**

- (1) Mounted on infinite heatsink
- (2) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,IA}$



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.70	-	V	
	I <sub>F</sub> = 5 A			0.84	0.95		
	I <sub>F</sub> = 2.5 A	T <sub>J</sub> = 125 °C		0.56	-		
	I <sub>F</sub> = 5 A			0.63	0.68		
Reverse current at rated V <sub>R</sub> per diode	$V_R = 100 \text{ V}$ $T_J = 25 \text{ °C}$ $T_J = 125 \text{ °C}$		0.0003	-			
		T <sub>J</sub> = 125 °C	I <sub>R</sub> <sup>(2)</sup>	0.5	-	- mA	
	V <sub>R</sub> = 150 V	T <sub>J</sub> = 25 °C		-	0.05		
	v <sub>R</sub> = 150 v	T <sub>J</sub> = 125 °C		1.25	4		
Typical junction capacitance	4.0 V, 1 MHz		CJ	280	-	pF	

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 5$  ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL V10DM153C			
Typical thermal registance per device	R <sub>0</sub> JC <sup>(1)</sup>	2.7	°C/W	
Typical thermal resistance per device	R <sub>0JA</sub> (2)(3)	58	C/ VV	

#### **Notes**

(1) Mounted on infinite heatsink

 $^{(2)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$  - junction-to-ambient

(3) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V10DM153C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V10DM153CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified

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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

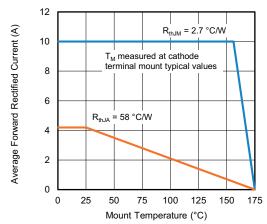


Fig. 1 - Maximum Forward Current Derating Curve

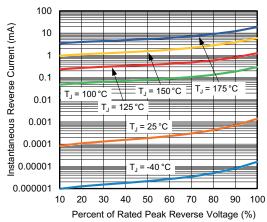


Fig. 4 - Typical Reverse Leakage Characteristics

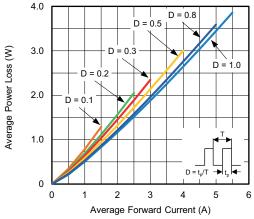


Fig. 2 - Average Power Loss Characteristics

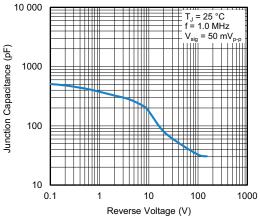


Fig. 5 - Typical Junction Capacitance

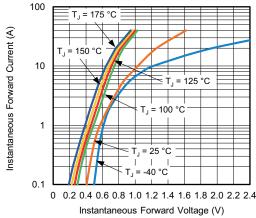


Fig. 3 - Typical Instantaneous Forward Characteristics

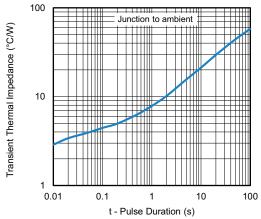


Fig. 6 - Typical Transient Thermal Impedance

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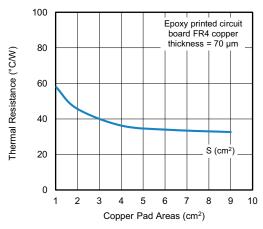
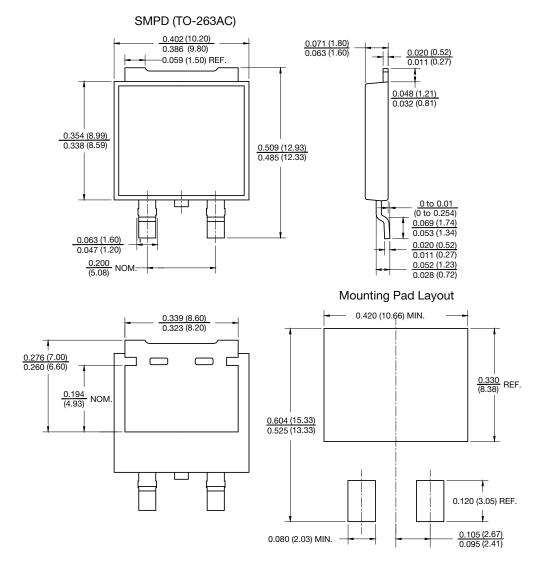


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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